

HOLOGRAM LASER

LT0H34P

Hologram Laser(3 beam) for MD players/recorders

■ Features

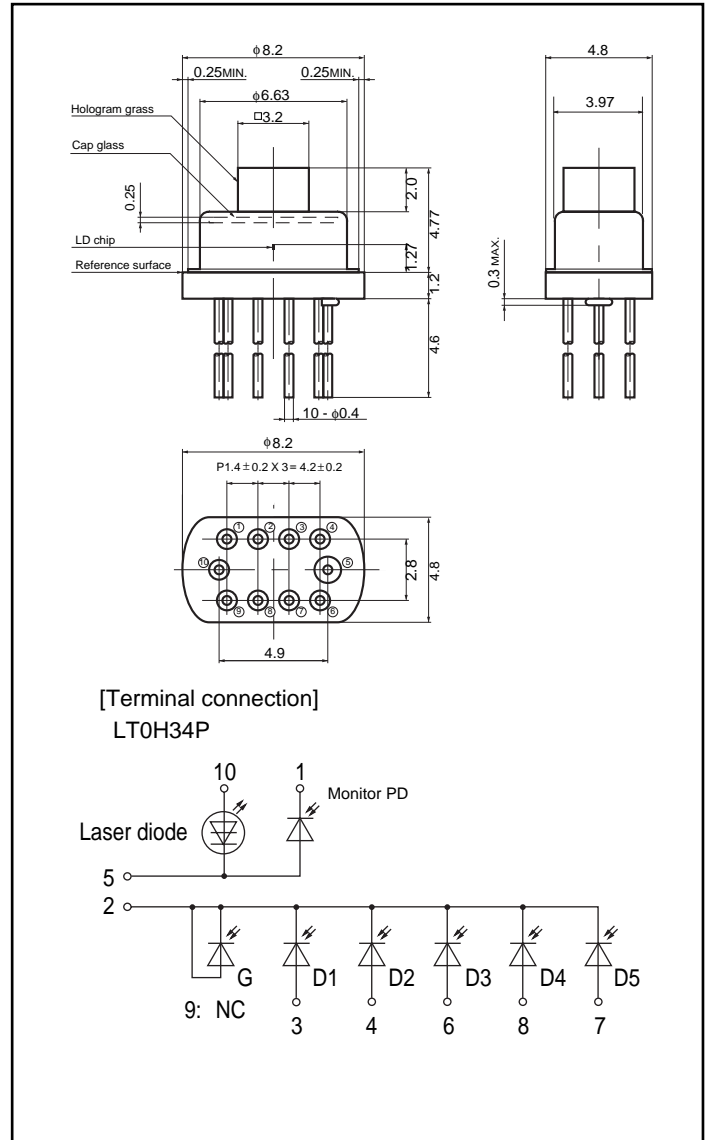
- (1) Compact package with high power output (MAX. 35mW)
- (2) Enables to design compact pick-up thanks to compact package. (Thickness; 4.8mm)
- (3) Since its semiconductor laser, signal detection photocell, and circuit array are assembled in a package, the optical pick is simple in assembling and adjustment
- (4) The adjustment during pickup assembly is eased and can easily be automated.

■ Applications

- (1) MD players/recorders

■ Outline Dimensions

(Unit: mm)



■ Absolute Maximum Ratings

Parameter	Symbol	Ratings	Units
Optical power output *1	P_H	32	mW
Reverse voltage	Laser	2	V
	Monitor photodiode	30	
	Photodiode for signal detection	15	
Operating temperature *2	T_{opr}	-10 to +60	$^{\circ}C$
Storage temperature *2	T_{stg}	-40 to +85	$^{\circ}C$
Soldering temperature *3	T_{sol}	260(5s or less)	$^{\circ}C$

- *1 Output power from hologram laser
 *2 Case temperature
 *3 At the position of 1.6mm from the bottom face of resin package.

(Notice)

- In the absence of device specification sheets, SHARP takes no responsibility for any defects that may occur in equipment using any SHARP devices shown in catalogs, data books, etc. Contact SHARP in order to obtain the latest device specification sheets before using any SHARP device.

- Specifications are subject to change without notice for improvement.

(Internet)

- Data for Sharp's optoelectronic/power devices is provided for internet. (Address <http://www.sharp.co.jp/ecg/>)

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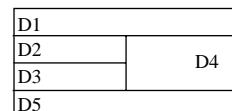
■ Electro-optical Characteristics

(Tc=25°C)

Parameter		Symbol	Condition	MIN	TYP	MAX	Units		
Laser	Threshold current		I _{th}	-	60	80	mA		
	Operating current		I _{op}	P _H =27.4mW *1	-	125	150	mA	
	Operating voltage		V _{op}		-	1.8	2.2	V	
	Wavelength *2		λ _p		770	785	800	nm	
	Monitor current		I _m	P _H =27.4mW *1, V _R =5V	-	0.14	-	mA	
	Radiation Characteristics	Angle	Parallel	θ _{//}	P _H =27.4mW *1	-	11	-	°
			Perpendicular			θ _⊥	-	26	-
	Emission Point accuracy	Angle	Δφ _{//}	-	-	-	±1	°	
			Δφ _⊥		-	-	±3	°	
		Position	Δx		-	-	±30	μm	
Δy			-		-	±30	μm		
		Δz	-	-	±80	μm			
Differential efficiency		η	18.3mW / (I _{op} (27.4mW) - I _{op} (9.1mW))	0.25	0.5	0.85	mW/mA		
Monitor Photodiode	Dark current		I _d	V _R =5V		-	-	150	nA
	Terminal capacitance		C _t	V _R =5V		-	20	-	pF
Photodiode for signal detection	Reverse voltage		V _R	I _R =10μA	A	15	-	-	V
					B				
					C				
	Dark current		I _d	V _R =1.5V	A	-	-	10	nA
					B				
					C				
	Terminal capacitance		C _t	V _R =1.5V, f=1MHz	A	1.0	-	8	pF
					B				
					C				
	Short circuit current *3 *4		I _{sc}	E _v =1000Lx	A	120	210	-	nA
					B				
					C				
Response time *5		t _r , t _f	V _R =1.5V, R _L =180Ω	A	-	-	660	ns	
				B					
				C					

- *1 Output power form LD chip
- *2 Oscillation mode: TEM₀₀
- *3 Values in each element. Elements other than subject elements shall be measured while the anode and the cathode are short-circuited to each other
- *4 Short-circuit currents between segments D1 and D5 or D3 and D4 shall be within ±10% of the average
- *5 E_v: Illuminance by CIE standard light source A (tungsten lamp)
- *6 Measuring method is shown below.

*7 Applicable divisions correspond to pattern segment No.



Segment No.
 D1, D5 A
 D2, D3 B
 D4 C

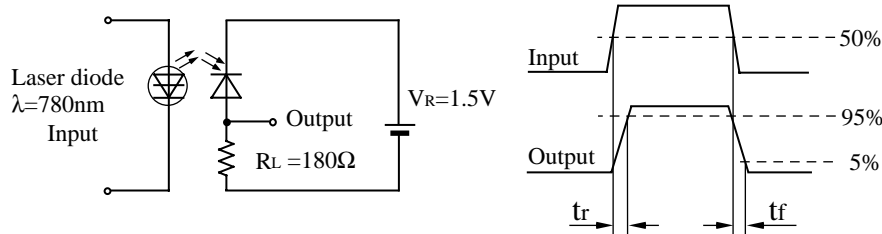


Fig.1

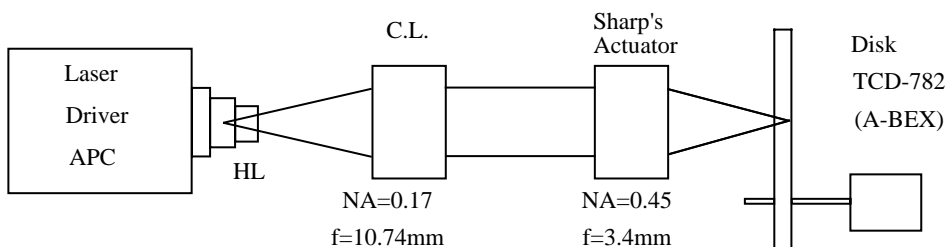
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■ Electro-optical Characteristics *1 (Tc=25°C)

Parameter	Condition	MIN	TYP	MAX	Units
Focus error signal offsetting *2	Values at FES output amplitude 5μAp-p	-0.4	0	+0.4	μm
Lead-in for focus error signal *3		10	19	30	μm
RF Output amplitude (D2+D3+D4)*4		5	10	-	μA p-p
RES Output amplitude (D1-D5) *5		0.3	0.55	1.0	μA p-p
Radial error balance *6		-20	-	20	%

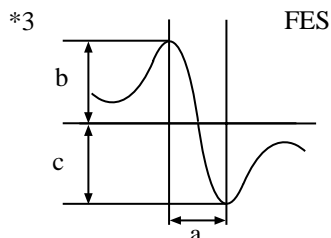
D1,D2,D3,D4,D5: Refer to pattern segment No. (Fig.1)

*1 Measuring method is shown below.



Measuring method of electro-optical characteristics

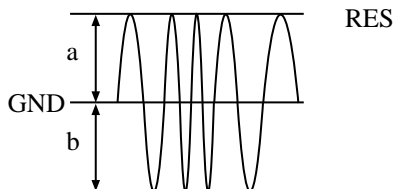
*2 Distance between FES=0 and jitter Min. point



*4 Focus/radial servo is ON-state

*5 RES output amplitude: under the condition that only focus servo is effected

*6
$$\frac{(a - b) / 2}{a + b}$$



Factors *2 to *6 are measured with high-reflection disk (TCD782 made by A-BEX) at 3μAp-p of FES output amplitude
3μAp-p of the FES output amplitude is set through focusing oscillation